NSN 5961-01-517-8512

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View Online at https://aerobasegroup.com/nsn/5961-01-517-8512 **Inclosure Material:** Plastic **Overall Length:** Between 1.496 inches and 1.505 inches **Overall Height:** Between 0.460 inches and 0.481 inches Overall Width: Between 0.990 inches and 1.001 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 70.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 gate to source voltage **Current Rating Per Characteristic:** 340.00 amperes drain current and 340.00 amperes source current **Power Rating Per Characteristic:** 700.0 watts total device dissipation **Product Name:** Semiconductor device, power mosfet single die **Special Features:** Ambeint temp -55 to +150 degree c; semi conductor device, power mosfet single die; hardness critical item **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 threaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: